Semiconductor Engineering 1

| Basic Course Information | 01005098 | Subject Catagory | Compulsory (M | 1 |
|---|---|---|---|---------------------------------|
| Class Format | Lecture | Credit Type and Number of Credits | 1 | |
| Department Period of Study | Mechatronics Semester 1 | Student Category Cleanse per Week | Year 5 1 | |
| Required Materials | TBA Hitoshi Nishizawa | Jirapat Anuntahirunra | | |
| Course Objective | | | | |
| The course provides students with intro devices including pn-junction and pnp/ | duction and basic knowledge non-junctions. | of physics in Semicondu | uctors and Semiconductor | |
| Evaluation (Rubric) | Ideal Level of Achievement (Very Good) | Standard Level of Achievement (Good) | Unacceptable Level of Achievement (Fail) |] |
| Electrons' behavior in semiconductors | Able to explain electrons' behavior in semiconductors | Able to explain electrons' behavior in | Need help explaining how electrons behave in | |
| Physics of PN junctions | Able to describe the characteristics of PN | Able to describe the characteristics of PN | Cannot use the band theory to describe the | |
| Physics of bipolar transistors | theory in detail. Able to describe the | band theory. Able to describe the | characteristics of HN junctions. Cannot use the band theory | |
| Physics of LEDs and solar cells | characteristics of bipolar transistors using the band theory in detail. | characteristics of bipolar transistors using the band theory. | to describe the characteristics of bipolar transistors. | |
| | characteristics of LEDs and solar cells using the band theory in detail. | characteristics of LEDs and solar cells using the band theory. | explain the characteristics of LEDs or solar cells, | 1 |
| M(2) Ability to design, propose and d | M(2) Ability to design, propose and develop electrical and electronic systems for robotica/ mechatronic systems | | | |
| Presse change | | | | |
| Teaching Method | | | |] |
| Outline | | Lecture and group work | | |
| Class Format: Please Note : | Students are require | d to ask any questions after | sufficient self-learning | |
| Course Plan Semester 1 | Contents and Mati | nod of Course | Goala | Related MCC |
| 1st Week | History of semiconductor dev vacuum tubes to semicondu | velopment (from ctors) | Can explain the outline of semiconductor development history, | V-D 4 |
| | | | | |
| 2nd Week | Solid state physics (electron volt, duality of electrons: waves and particles) | | Can explain the duality of electrons. | N-C 2 #: |
| 3rd Week | Atomic structure and crystal structure of semiconductors | | Can explain the atomic and crystal structure of semiconductors, | |
| | | | | V-C 3 55 |
| 4th Week | Electronic band structure and the behavior of electrons | | Can explain the electronic band structure of semiconductors, | V-C 3 56 |
| 5th Week | Carrier concentration in semiconductors and its effect on conductivity | | Can explain the effect of carrier concentration on conductivity. | V-C 3 56 V-C 3 58 |
| 6th Week | Carrier generation/recombination, diffusion current, and PN junction | | Can explain how PN Junction works. | V-C 3 59 V-C 3 60 |
| 7th Week | School event 5 | | | |
| 8th Week | Preparing for Mid-term examination | | Review problems for the mid term examination, | |
| 9th Week | Mid-term examination | | Can slove problems at the mid-term examination. | |
| 10th Week | Mid-term examination week | | | |
| 11th Week | Return exam papers and feedback | | Review and summarize the learning. | |
| 12th Week | Quantitative analysis of a PN junction, and reverse breakdown current | | Can explain the inner resitance and reverse current of a PN junction. | V-C 3 60 |
| 13th Week | National Holiday | | | |
| 14th Week | Metal-semiconductor contact and Schottky barrier | | Can explain the voltage- current characteristics at metal-semiconductor contacts. | |
| 15th Week | Fundamental function of bipoler junction transistors | | Can explain the electronic behavior of bipolar junction transistors using the band theory. | V-C 3 61 |
| 16th Week | Amplifier circuits using a bloolar junction transistor | | Can explain the electronic behavior of bipolar junction transistors using the band theory. | V-C 3 61 |
| 17th Week | Dynamic characteristics of bibolar junction transistors | | Can explain the switching phenomena of bipolar junction transistors, | |
| 18th Week | Light emitting diodes (LED) and Solar cells | | Can estimate the collector current of bipolar junction transistors. | |
| 19th Week | Preparing for final examination | | Beview related circuit problems for the final examination. | |
| 20th Week | Final Examination | | Can slove problems at the final examination, | Do |
| | Examination | Quiz | Mutual Evolucions botwson students | Do not Report Particle Other |
| meas: ADIEV | 0.5 | 20 | | 253 |